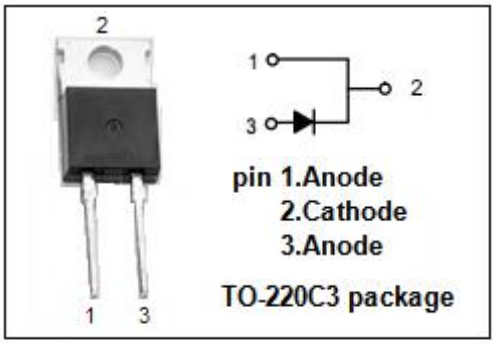
# Schottky Barrier Rectifier DSS16-01A

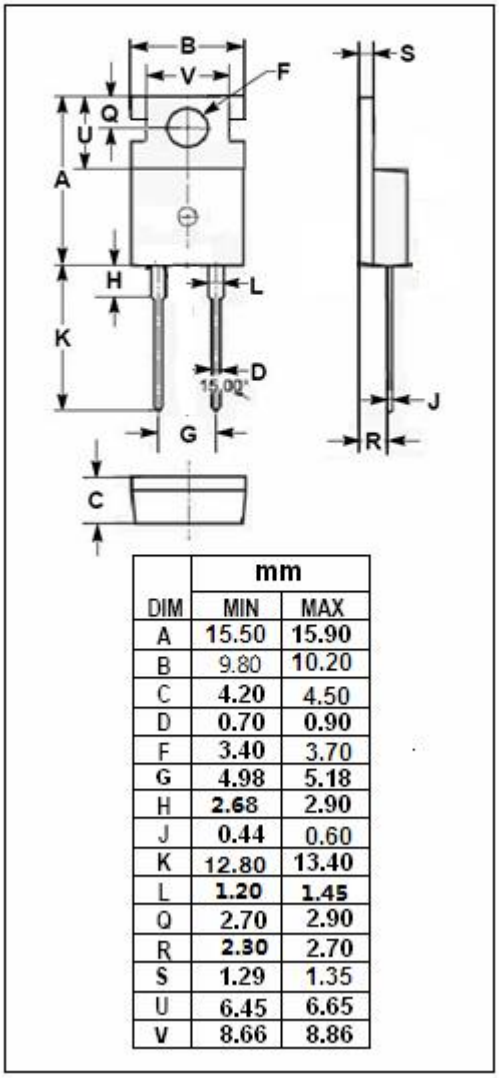
## FEATURES

- Metal of silicon rectifier, majonty carrier conduction
- Guard ring for transient protection
- Low power loss high efficiency
- High Surge Capability,High Current Capability
- Minimum Lot-to-Lot variations for robust device performance and reliable operation




## APPLICATIONS

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching




| DIM | mm MIN | mm MAX |
|---|---|---|
| A | 15.50 | 15.90 |
| B | 9.80 | 10.20 |
| C | 4.20 | 4.50 |
| D | 0.70 | 0.90 |
| F | 3.40 | 3.70 |
| G | 4.98 | 5.18 |
| H | 2.68 | 2.90 |
| J | 0.44 | 0.60 |
| K | 12.80 | 13.40 |
| L | 1.20 | 1.45 |
| Q | 2.70 | 2.90 |
| R | 2.30 | 2.70 |
| S | 1.29 | 1.35 |
| U | 6.45 | 6.65 |
| V | 8.66 | 8.86 |

**ABSOLUTE MAXIMUM RATINGS(Ta=25℃)**

| SYMBOL | PARAMETER | VALUE | UNIT |
|---|---|---|---|
| $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | 100 | V |
| $I_{F(AV)}$ | Average Rectified Forward Current<br>(Rated $V_R$) $T_C$= 135℃ | 16 | A |
| $I_{FSM}$ | Nonrepetitive Peak Surge Current<br>(Surge applied at rated load conditions half-wave, single phase, 50Hz) | 230 | A |
| $P_D$ | Total Dissipation @$T_C$=25℃ | 105 | W |
| $T_J$ | Junction Temperature | -55~175 | ℃ |
| $T_{stg}$ | Storage Temperature Range | -55~175 | ℃ |

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## THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---|---|---|---|
| $R_{th\ j\text{-}c}$ | Thermal Resistance,Junction to Case | 1.4 | ℃/W |

## ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 μ s,Duty Cycle≤1%)

| SYMBOL | PARAMETER | CONDITIONS | MAX | UNIT |
|---|---|---|---|---|
| $V_F$ | Maximum Instantaneous Forward Voltage | $I_F$= 15A ; $T_C$= 25℃<br>$I_F$= 15A ; $T_C$= 125℃<br>$I_F$= 30A ; $T_C$= 125℃ | 0.79<br>0.64<br>0.76 | V |
| $I_R$ | Maximum Instantaneous Reverse Current | Rated DC Voltage, $T_C$= 25℃<br>Rated DC Voltage, $T_C$= 125℃ | 0.5<br>5 | mA |